

650 V, 30 A trench field-stop IGBT with full rated silicon diode Rev. 1 — 17 January 2025 Product data sheet

1. General description

The NGW30T65M3DFP is a robust Insulated-Gate Bipolar Transistor (IGBT) featuring thirdgeneration technology. It combines carrier stored trench-gate and field-stop (FS) structures. The NGW30T65M3DFP is rated to 175 °C with optimized IGBT turn-off losses, and has a short circuit withstand time of 5 μ s. This hard-switching 650 V, 30 A IGBT is optimized for high-voltage, highfrequency industrial power inverter applications and servo motor drive applications.

2. Features

- Device current is rated at 30 A
- · Low conduction and switching losses
- Stable and tight parameters for easy parallel operation
- Maximum junction temperature 175 °C
- Fully rated and fast reverse recovery diode
- 5 µs short circuit withstand time
- HV-H3TRB qualified

3. Applications

- Motor drives for industrial and consumer appliances
 - Servo motors operating between 5-20 kW (up to 20 kHz) for robotics, elevators, operating grippers, in-line manufacturing, etc.
- Power inverters, such as
 - Uninterruptible Power Supply (UPS) inverter
 - EV charging converter
- Induction heating
- Welding

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{CES}	collector-emitter voltage	T _{vj} = 25 °C	-	650	V
T _{vj}	operating junction temperature		-40	175	°C
t _{sc}	short circuit withstand time	V_{GE} = 15 V; V_{CC} = 400 V; $T_{vj} \le 150 \text{ °C}$	-	5.0	μs

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5. Pinning information

Table 2.	Pinning info	rmation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	mb	
2	С	collector		С
3	E	emitter		
mb	С	mounting base; connected to collector		G

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
NGW30T65M3DFP	TO-247-3L	Plastic single-ended through-hole package; heatsink mounted; 1 mounting hole; 3-lead TO-247-3L	<u>SOT429-2</u>		

7. Limiting values

Table 4. Limiting values

Symbol	Parameter		Conditions	Min	Max	Unit
IGBT	1					
V _{CES}	collector-emitter voltage		T _{vj} = 25 °C	-	650	V
I _C	collector current	[1]	T _c = 25 °C	-	57	А
			T _c = 100 °C	-	38	А
I _{CRM}	repetitive peak collector current	[2]		-	90	А
t _{sc}	short circuit withstand time	[3]	V _{GE} = 15 V; V _{CC} = 400 V; T _{vj} ≤150 °C	-	5.0	μs
V _{GE}	gate-emitter voltage			-20	20	V
P _{tot}	total power dissipation		T _c = 25 °C	-	199	W
			T _c = 100 °C	-	99	W
T _{vj}	operating junction temperature			-40	175	°C
T _{stg}	storage temperature			-55	150	°C
T _{solder}	soldering temperature			-	260	°C
Diode						
l _F	diode forward current	[1]	T _c = 25 °C	-	50	А
			T _c = 100 °C	-	30	A
I _{FRM}	repetitive peak forward current	[2]		-	90	А

Value is limited by bondwire and $T_{\nu j(\text{max})}$ [1]

[2] [3]

Time duration is limited by $T_{vj(max)}$. Short circuit cycles \leq 1000, time between tests \geq 1 s.

8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
М	mounting torque, M3 screw		-	0.6	-	Nm
R _{th(j-c)} thermal resistance from junction to case	IGBT	-	0.64	0.75	K/W	
			-	1.22	1.44	K/W
R _{th(j-a)}	thermal resistance from junction to ambier	it in free air	-	-	40	K/W

9. Electrical characteristics

Table 6. Characteristics

All values at T_{vj} = 25 °C, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics					
V _{(BR)CES}	collector-emitter breakdown voltage	$V_{GE} = 0 \text{ V}; I_{C} = 0.2 \text{ mA}$	650	-	-	V
V _{CEsat}	collector-emitter saturation	V _{GE} = 15 V; I _C = 30 A; T _{vj} = 25 °C	-	1.50	1.8	V
	voltage	V _{GE} = 15 V; I _C = 30 A; T _{vj} = 175 °C	-	1.91	-	V
V _F	diode forward voltage	V _{GE} = 0 V; I _F = 30 A; T _{vj} = 25 °C	-	1.69	2.0	V
		V _{GE} = 0 V; I _F = 30 A; T _{vj} = 175 °C	-	1.46	-	V
V _{GE(th)}	gate-emitter threshold voltage	I _C = 0.3 mA; V _{CE} = V _{GE} ; T _{vj} = 25 °C	4.3	5.0	5.7	V
I _{CES}	zero gate voltage collector current	V _{CE} = 650 V; V _{GE} = 0 V; T _{vj} = 25 °C	-	4	-	nA
		V _{CE} = 650 V; V _{GE} = 0 V; T _{vj} = 175 °C	-	0.3	-	mA
I _{GES}	gate-emitter leakage current	V _{CE} = 0 V; V _{GE} = 20 V	-	-	100	nA
9 _{fs}	transconductance	V _{CE} = 20 V; I _C = 30 A; T _{vj} = 25 °C	-	14.6	-	S
r _g	internal gate resistor		-	1.6	-	Ω
Dynamic	characteristics	,	1		1	1
C _{ies}	input capacitance	V _{CE} = 25 V; V _{GE} = 0 V; f = 1 MHz	-	2196	-	pF
C _{oes}	output capacitance		-	83	-	pF
C _{res}	reverse transfer capacitance		-	22	-	pF
Q _G	gate charge	V _{CC} = 520 V; I _C = 30 A; V _{GE} = 15 V	-	89	-	nC
L _{sCE}	internal stray inductance	measured 5 mm from case	-	7.9	-	nH
I _{C(sc)}	short circuit collector current	V _{GE} = 15 V; V _{CC} = 400 V; t _{sc} ≤ 5 µs; T _{vj} ≤ 150 °C	-	153	-	А

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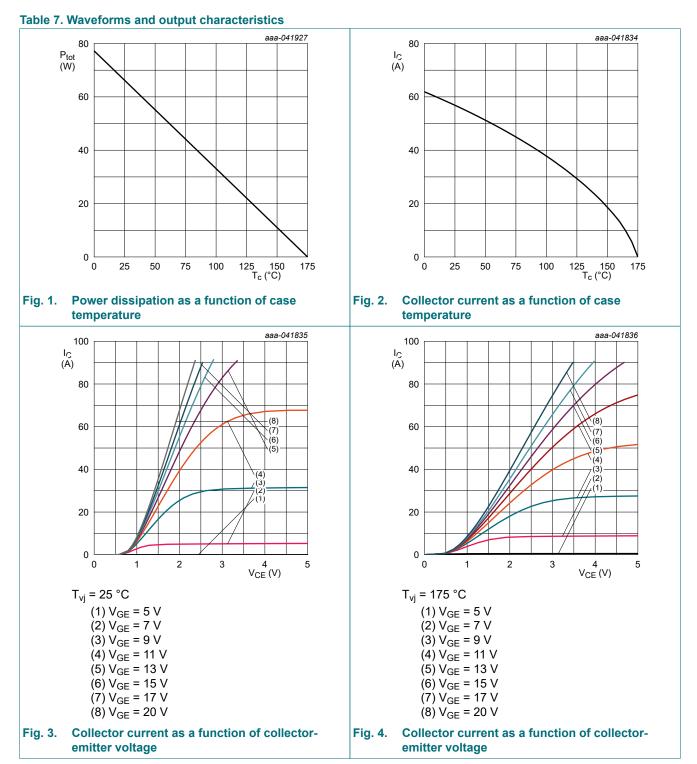
t_f

t_{rr}

NGW30T65M3DFP

Symbol Parameter Conditions Min Max Unit Тур IGBT switching characteristics, inductive load turn-on delay time V_{GE} = 15/0 V; V_{CC} = 400 V; T_{vi} = 25 °C 16 ns t_{d(on)} -_ $$\begin{split} & I_{C} = 30 \text{ A}; \text{ } \text{R}_{G(on)} = 10 \text{ } \Omega; \\ & \text{ } \text{R}_{G(off)} = 10 \text{ } \Omega; \\ & \text{ see Fig. 27 and Fig. 28} \end{split}$$ T_{vi} = 175 °C 15 _ _ ns T_{vi} = 25 °C rise time 17 _ _ ns T_{vi} = 175 °C 18 -ns T_{vi} = 25 °C turn-off delay time -137 ns t_{d(off)} T_{vi} = 175 °C 168 _ _ ns T_{vi} = 25 °C fall time 36 -ns T_{vi} = 175 °C -77 ns -T_{vi} = 25 °C Eon turn-on switching energy loss _ 0.79 mJ _ T_{vi} = 175 °C _ 1.58 _ mJ Eoff turn-off switching energy loss T_{vi} = 25 °C 0.42 mJ --T_{vi} = 175 °C 0.70 mJ --E_{ts} total switching energy loss T_{vj} = 25 °C 1.21 mJ -T_{vi} = 175 °C 2.29 mJ --Diode switching characteristics, inductive load T_{vi} = 25 °C reverse recovery time V_R = 400 V; I_F = 30 A; 105 _ _ ns di_F/dt = 500 A/µs; see Fig. 26 T_{vi} = 175 °C 208 ns -T_{vi} = 25 °C 774 Q_{rr} reverse recovery charge nC --T_{vi} = 175 °C 2750 nC _ _ T_{vi} = 25 °C peak reverse recovery current 18 А I_{rrm} _ -T_{vi} = 175 °C A 30 _ -T_{vi} = 25 °C 0.08 E_{rec} reverse recovery energy loss mJ T_{vi} = 175 °C 0.40 mJ _ _ di_{rrf}/dt T_{vi} = 25 °C 398 A/µs fall rate of reverse recovery -current T_{vi} = 175 °C 230 A/µs --

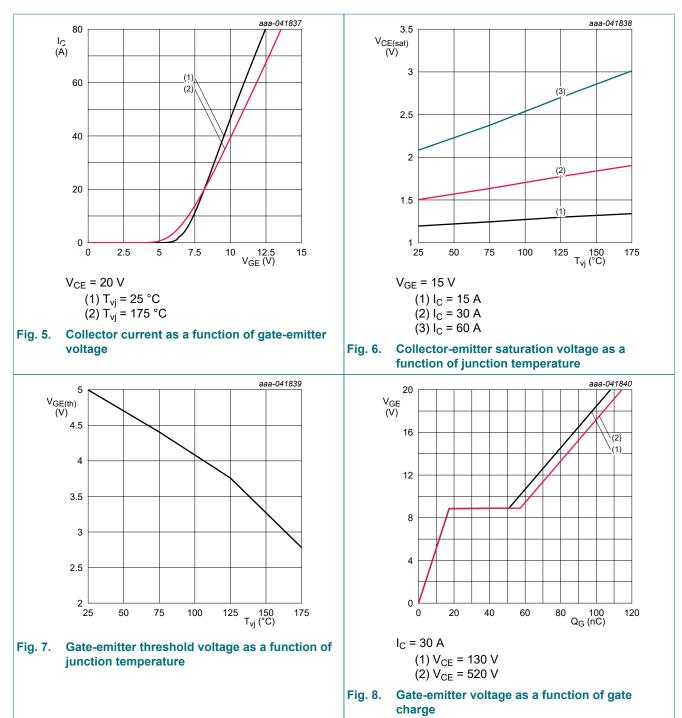
650 V, 30 A trench field-stop IGBT with full rated silicon diode



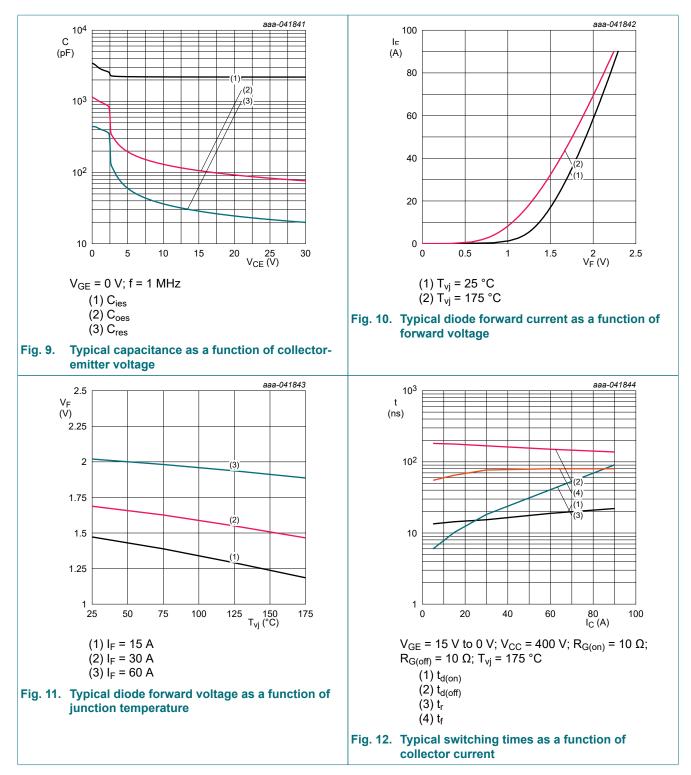
9.1. Characteristic diagrams

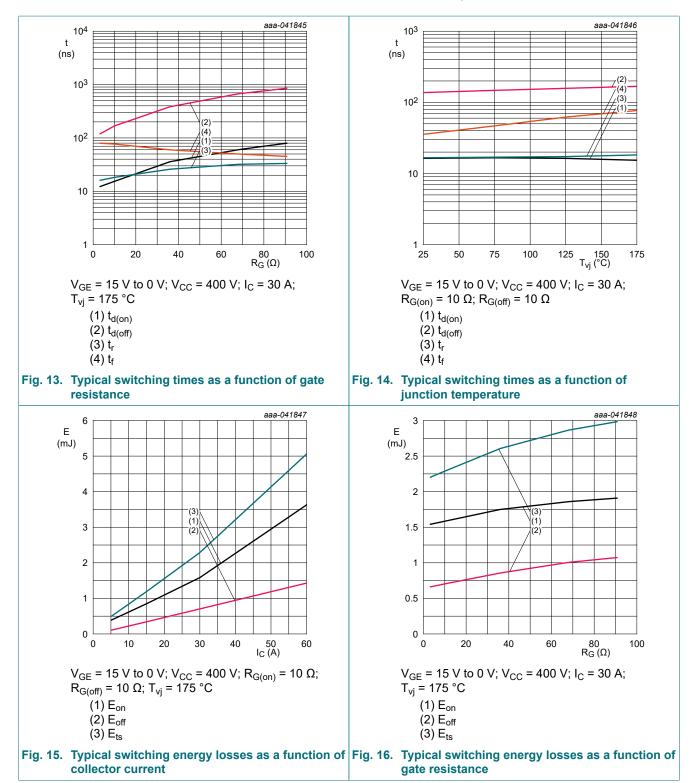
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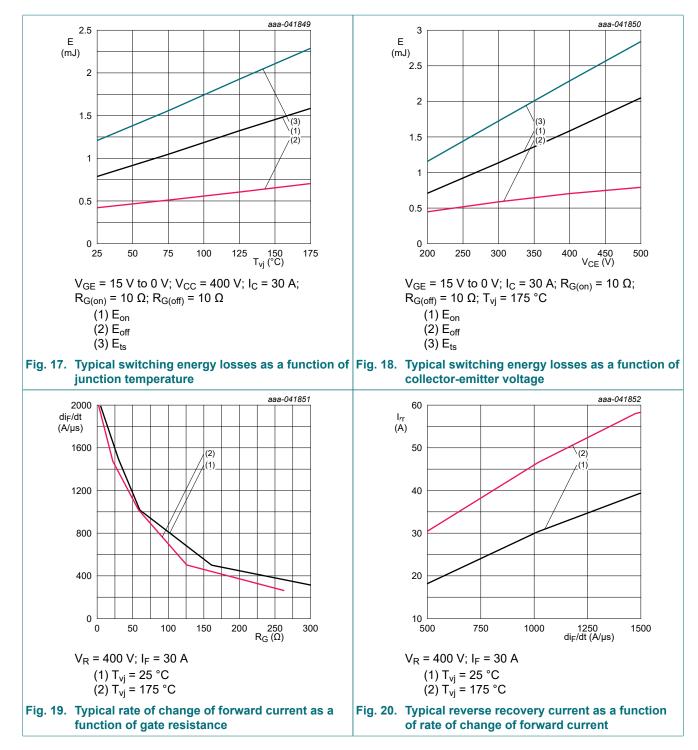


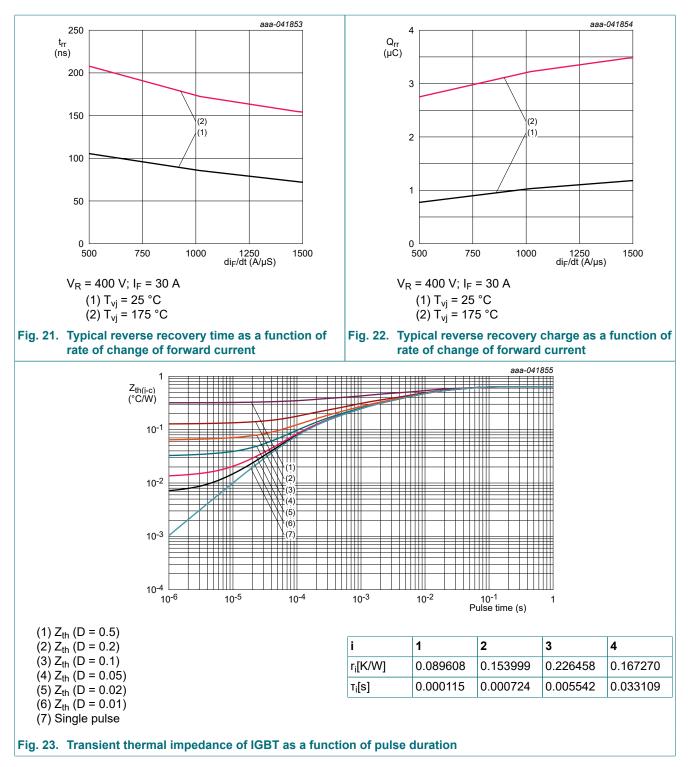
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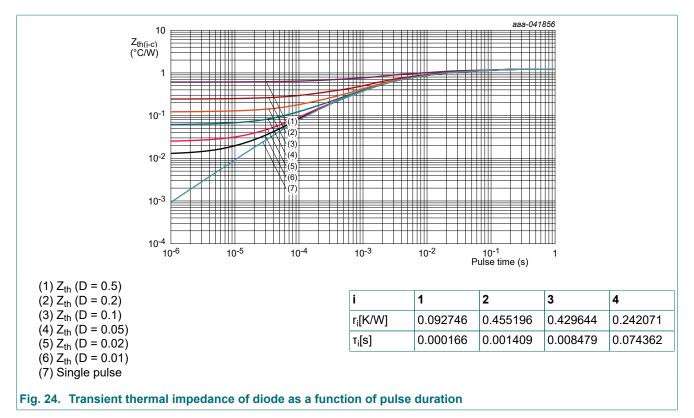




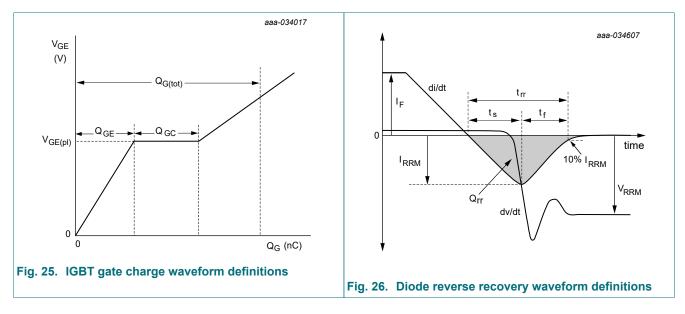
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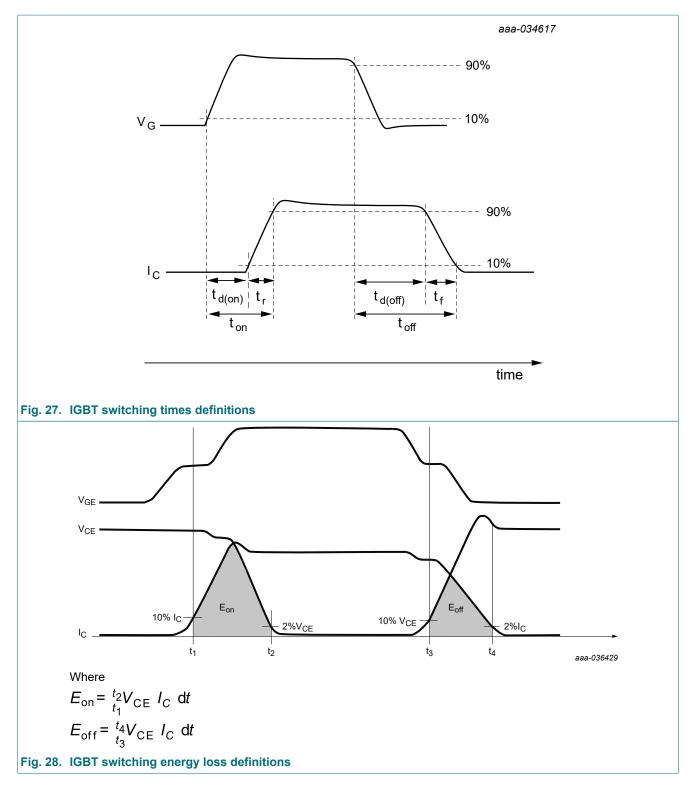




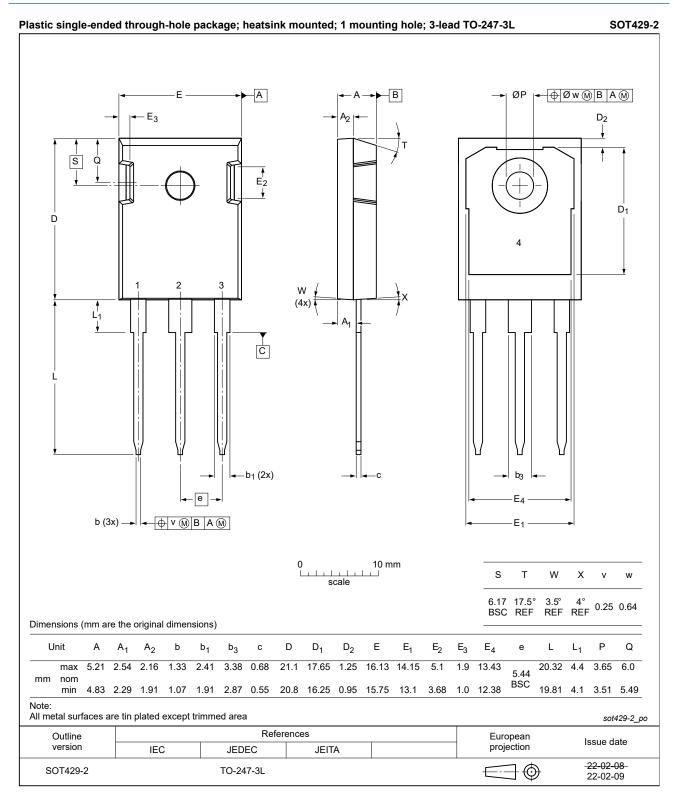








10. Package outline





11. Revision history

Table 8. Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes	
NGW30T65M3DFP v. 1	20250117	Product data sheet	-	-	

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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